74HC4050

Hex non-inverting HIGH-to-LOW level shifter

Rev. 4 — 5 February 2016

Product data sheet

1. General description

The 74HC4050 is a hex buffer with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V which enables the device to be used in HIGH-to-LOW level shifting applications.

2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2 000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

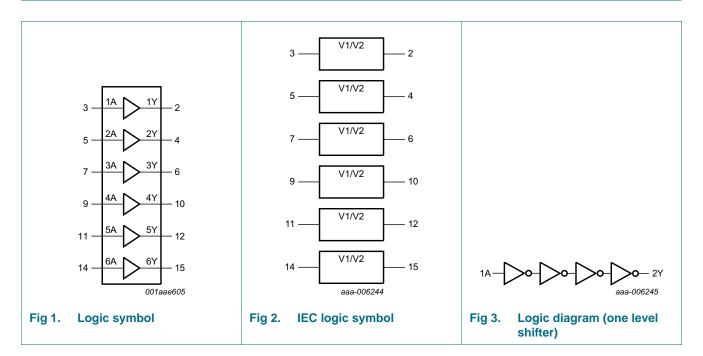
Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74HC4050D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74HC4050DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
74HC4050PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					



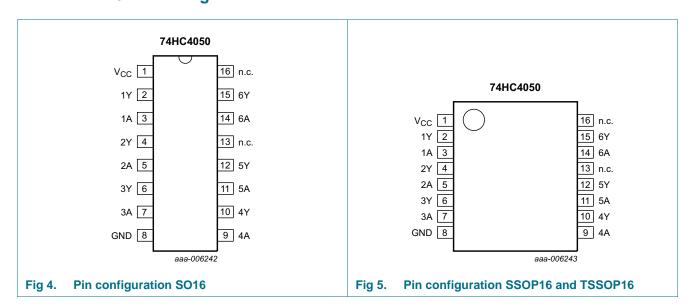
Hex non-inverting HIGH-to-LOW level shifter

4. Functional diagram



5. Pinning information

5.1 Pinning



Hex non-inverting HIGH-to-LOW level shifter

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V _{CC}	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

6. Functional description

Table 3. Function table [1]

Input	Output
nA	nY
L	L
Н	Н

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

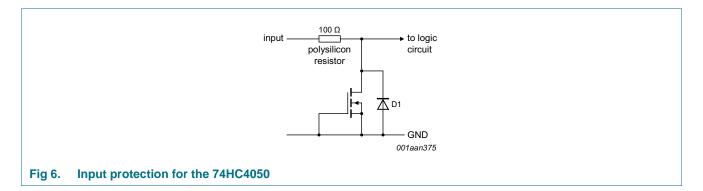
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
V _{IK}	input clamping voltage			-0.5	+16	V
I _{IK}	input clamping current	V _I < -0.5 V		-20	-	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-	-50	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO16, SSOP16 and TSSOP16 packages	[1]	-	500	mW

^[1] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

Hex non-inverting HIGH-to-LOW level shifter



8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	15	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; V_I = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; V_I = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 10.0 \text{ V}$	-	-	81	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 15.0 \text{ V}$	-	-	83	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.3	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.1	-	4.2	-	4.2	-	V
V _{IL}		V _{CC} = 2.0 V	-	0.7	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	1.8	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.3	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

74HC4050

Hex non-inverting HIGH-to-LOW level shifter

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	meter Conditions		T _{amb} = 25 °C			$T_{amb} = -40 ^{\circ}\text{C} \text{ to}$ +85 $^{\circ}\text{C}$		T _{amb} = -40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$	-	-	0.1	-	0.1	-	0.1	V
	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	-	0.1	-	0.1	V	
	$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	-	0.1	-	0.1	-	0.1	V	
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
		$V_I = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ 6.0 V	-	-	±0.5	-	±5.0	-	±5.0	μΑ
I _{CC}	supply current	V_I = 15 V or GND; I_O = 0 A; V_{CC} = 6.0 V	-	-	2.0	-	20	-	40	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 8.

Symbol	Parameter	Conditions		T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
		Min	Тур	Max	Min	Max	Min	Max		
t _{pd}	propagation	nA to nY; see Figure 7 [1]								
	delay	V _{CC} = 2.0 V	-	25	85	-	105	-	130	ns
	V _{CC} = 4.5 V	-	9	17	-	21	-	26	ns	
		V _{CC} = 5 V; C _L = 15 pF	-	7	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	7	14	-	18	-	22	ns
t _t	transition	Yn; see Figure 7 [2]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns

Hex non-inverting HIGH-to-LOW level shifter

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 8.

Symbol	Parameter	Conditions	T _{an}	_{nb} = 25	°C		: –40 °C 85 °C		: –40 °C ∣25 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC}	-	14	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

fo = output frequency in MHz;

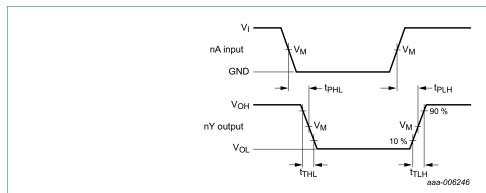
C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

11. Waveforms



Measurement points are given in Table 8.

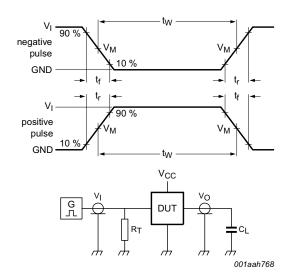
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 7. The input (nA) to output (nY) propagation delays

Table 8. Measurement points

Туре	Input	Output	
	V _M	V _M	
74HC4050	0.5V _{CC}	0.5V _{CC}	

Hex non-inverting HIGH-to-LOW level shifter



Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 8. Test circuit for measuring switching times

Table 9. Test data

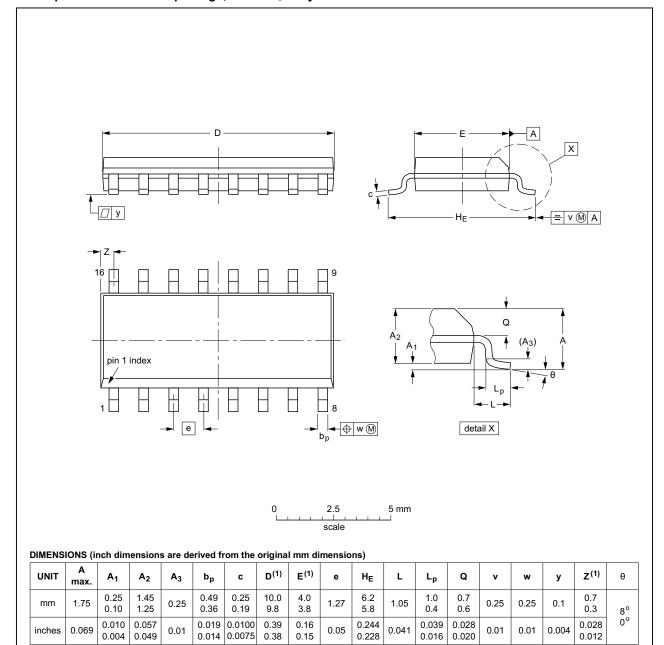
Туре	Input L		Load	Test
	V _I	t _r , t _f	C _L	
74HC4050	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

Hex non-inverting HIGH-to-LOW level shifter

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

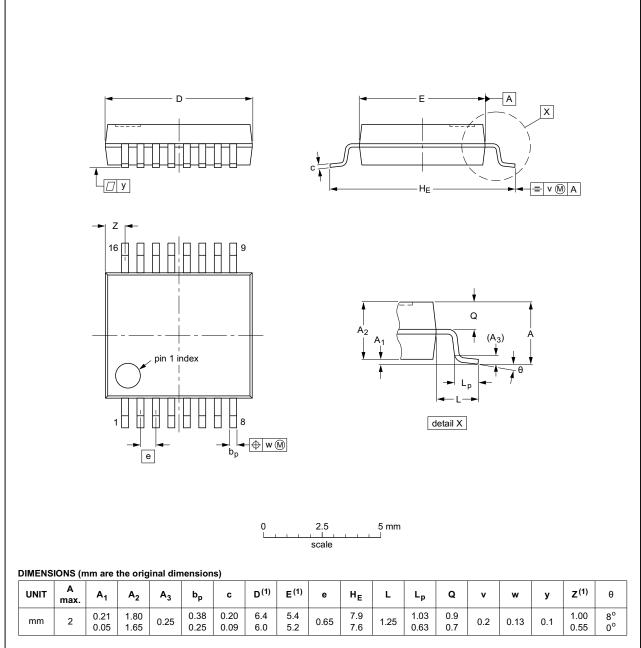
^{1.} Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	DUTLINE REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	IEC JEDEC JEITA		PROJECTION	133UE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Fig 9. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



Note

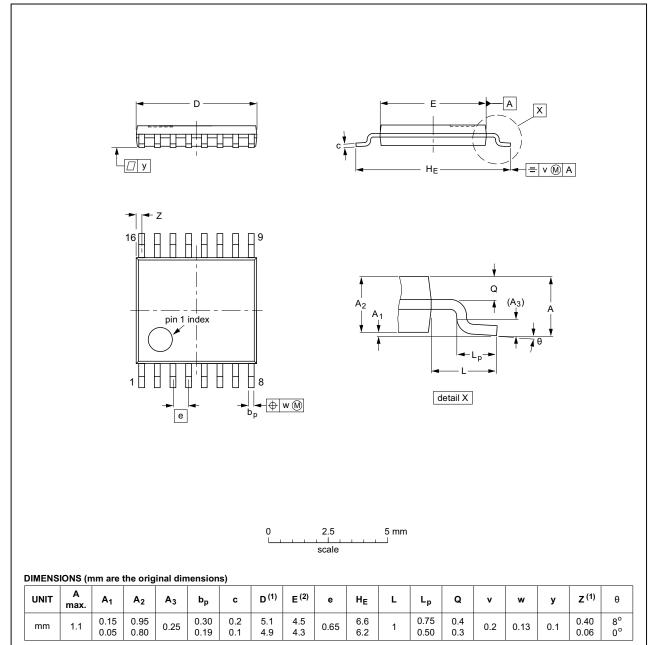
^{1.} Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				99-12-27 03-02-19

Fig 10. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT403-1		MO-153				99-12-27 03-02-18

Fig 11. Package outline SOT403-1 (TSSOP16)

Hex non-inverting HIGH-to-LOW level shifter

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4050 v.4	20160205	Product data sheet	-	74HC4050 v.3
Modifications:	Type number	er 74HC4050N (SOT38-4)	removed.	
74HC4050 v.3	20130131	Product data sheet	-	74HC4050_CNV v.2
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 			
 Legal texts have been adapted to the new company name where appropriate. 			where appropriate.	
74HC4050_CNV v.2	19970826	Product specification	-	-

Hex non-inverting HIGH-to-LOW level shifter

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

74HC4050

Hex non-inverting HIGH-to-LOW level shifter

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

Hex non-inverting HIGH-to-LOW level shifter

17. Contents

1	General description
2	Features and benefits
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 2
5.1	Pinning
5.2	Pin description
6	Functional description 3
7	Limiting values
8	Recommended operating conditions 4
9	Static characteristics 4
10	Dynamic characteristics 5
11	Waveforms 6
12	Package outline 8
13	Abbreviations
14	Revision history 11
15	Legal information 12
15.1	Data sheet status
15.2	Definitions 12
15.3	Disclaimers
15.4	Trademarks13
16	Contact information
17	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.